

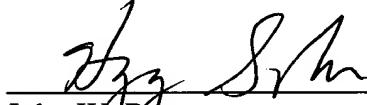
**CONCLUSION**

As all of the outstanding rejections have been traversed and all of the claims are believed to be in condition for allowance, the Applicants respectfully request issuance of a Notice of Allowability. If the undersigned attorney can assist in any matters regarding examination of this application, the Examiner is encouraged to call at the number listed below.

Respectfully submitted,

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**VERSION WITH MARKINGS TO SHOW CHANGES MADE****IN THE SPECIFICATION:**

On page 1, paragraph beginning at line 6 has been amended as follows:

U.S. Patent Application Serial No. [ ] **09/974,818**, entitled "INJECTION COLD EMITTER WITH NEGATIVE ELECTRON AFFINITY BASED ON WIDE-GAP SEMICONDUCTOR STRUCTURE WITH CONTROLLING BASE" (Attorney Docket No. 10007287-1).

**IN THE CLAIMS:**

1. (Once Amended) An electron emitter comprising:  
a p region;  
a dielectric layer formed above said p region; **[and]**  
a metallic layer formed above said dielectric layer; **and**  
**means for emitting electrons through said metallic layer.**